

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>		Docket Number (Optional) SETI-0005	Application Number	
		Applicant(s) Gaska et al.		
		Filing Date Herewith	Group Art Unit	
*EXAMINER INITIAL	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)			
	<p>"Introduction to Solid State Lighting," A. Zukausas et al., John Wiley & Sons, Inc., New York (2002), pp. 37-116.</p>			
	<p>"Improved Characteristics of InGaN Multiple-Quantum-Well Light-Emitting Diode by GaN/AlGaN Distributed Bragg Reflector Grown on Sapphire," N. Nakada et al., Applied Physics Letters, Vol. 76, No. 14, April 3, 2000, pp. 1804-1806.</p>			
	<p>"AlGaN Single-Quantum-Well Light Emitting Diodes With Emission at 285 nm," V. Adivarahan et al., Applied Physics Letters, Vol. 81, No. 19, November 4, 2002, pp. 3666-3668.</p>			
	<p>"Strain Energy Band Engineering Approach to AlN/GaN/InN Heterojunction Devices," A. Khan et al., Frontiers in Electronics: Future Chips Proceedings of the 2002 Workshop on Frontiers in Electronics (Wofe-02) St. Croix, Virgin Islands, World Scientific Pub Co; (January 15, 2003), ISBN: 9812382224, Vol. 26. Series Selected Topics in Electronics and Systems, pp. 195-214.</p>			
	<p>"A Vertical Injection Blue Light Emitting Diode in Substrate Separated InGaN Heterostructures," Y. -K. Song et al., Applied Physics Letters, Vol. 74, no. 24, June 14, 1999, pp. 3720-3722.</p>			
EXAMINER		DATE CONSIDERED		
*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.				